



4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Product Summary

V _{BR} (Min)	IPP (Max)	Ст (Тур)
5V	5.5A	0.55pF

Description

The DT1240A-04LP is a high-performance device suitable for protecting four high-speed I/Os. These devices are assembled in U-DFN2510-10 and U-DFN2510-10 (Type CJ) packages and have high ESD surge capability and low capacitance.

Applications

Typically used at high-speed ports such as USB2.0, USB3.0, USB3.1, IEEE1394 (Firewire $^{\circledR}$, iLink), Serial ATA, DVI $^{\intercal}$, HDMI $^{\intercal}$ 1.4, HDMI $^{\intercal}$ 2.0 and PCI $^{\intercal}$.

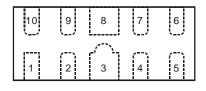
Features

- Clamping Voltage: 7.5V at 10A 100ns, TLP 8.2V at 5.5A (8µs/20µs)
- IEC 61000-4-2 (ESD): Air ±16kV, Contact ±14kV
- IEC 61000-4-5 (Lighting): 5.5A (8/20μs)
- 4 Channels of ESD Protection
- Low Channel Input Capacitance of 0.55pF Typical
- TLP Dynamic Resistance: 0.2Ω
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

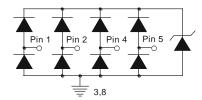
Mechanical Data

- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Schematic
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 4
- Weight: 0.038 grams (Approximate)

Pin #	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss



Pin Description (Top View)



Device Schematic

Ordering Information (Note 4)

Part Number	Compliance	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DT1240A-04LP-7	Standard	QE5	7	8	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

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Marking Information

QE5 YM

QE5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

QE5 YWX

QE5 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 1 = 2021) W = Week

(ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key for YM

Year	2016		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	D			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Date Code Key for YWX

Year	2016	 2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	6	 1	2	3	4	5	6	7	8	9	0

Week	1-26	27-52	53
Code	A-Z	a-z	z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	T	U	V	W	X	Y	Z

Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Condition
Peak Pulse Current, per IEC 61000-4-5	I _{PP}	5.5	Α	I/O to V _{SS} , 8/20µs
Peak Pulse Power, per IEC 61000-4-5	Ppp	52	W	I/O to Vss, 8/20µs
Operating Voltage (DC)	V _D C	3.6	V	I/O to Vss
ESD Protection – Contact Discharge, per IEC 61000-4-2	Vesd_contact	±14	kV	I/O to Vss
ESD Protection – Air Discharge, per IEC 61000-4-2	Vesd_air	±16	kV	I/O to Vss
Operating Temperature	Тор	-55 to +85	°C	_
Storage Temperature	T _{STG}	-55 to +150	°C	_

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	Reja	360	°C/W

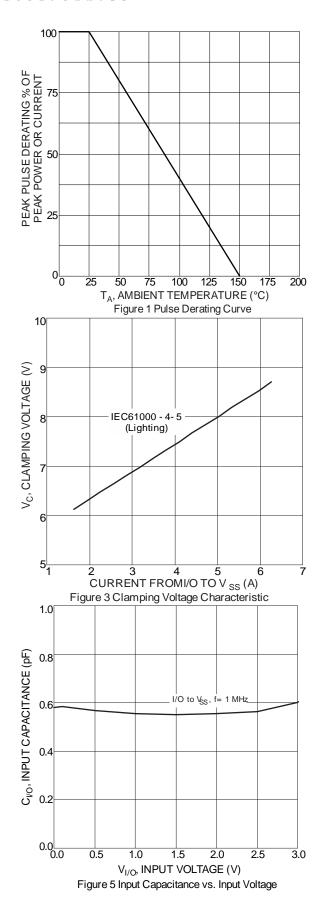
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

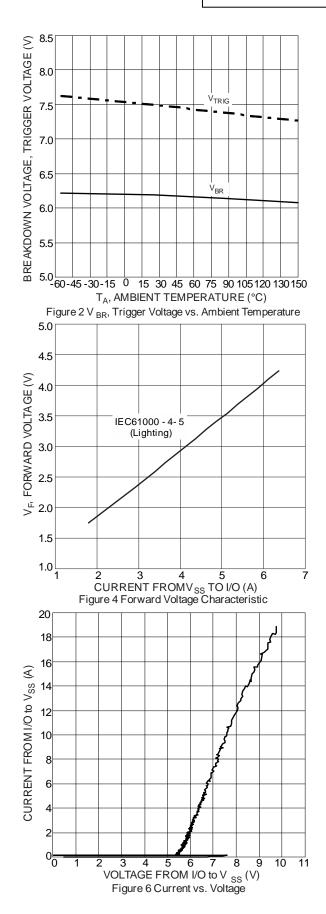
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}	_	_	3.3	V	_
Reverse Current	IR	_	_	1.0	μΑ	V _R = 3.3V, I/O to V _{SS}
Reverse Breakdown Voltage	V _{BR}	5	_	_	V	I _R = 1mA, I/O to V _{SS}
Forward Clamping Voltage	V _F	-1.0	-0.85	_	V	$I_F = -15$ mA, I/O to V_{SS}
Reverse Clamping Voltage (Note 6)	Vc	_	8.2	9.5	V	IPP = 5.5A, I/O to Vss, 8/20µs
ESD Clamping Voltage	VESD	_	7.5	_	V	TLP, 10A, tp = 100ns, I/O to Vss
Dynamic Reverse Resistance	R _{DIF-R}	_	0.2	_	Ω	TLP, 10A, tp = 100ns, I/O to Vss
Dynamic Forward Resistance	R _{DIF-F}	_	0.2	_	Ω	TLP, 10A, t _P = 100ns, V _{SS} to I/O
Channel Input Capacitance	C _{I/O}	_	0.55	0.65	pF	V _{I/O} = 2.5V, V _{SS} = 0V, f = 1MHz
Delta C _{I/O}	CI/OMAX-CI/OMIN	_	0.04	_	pF	CI/OMAX-CI/OMIN

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's website at http://www.diodes.com/package-outlines.html.

^{6.} Clamping voltage value is based on an 8µs x20µs peak pulse current (IPP) waveform.



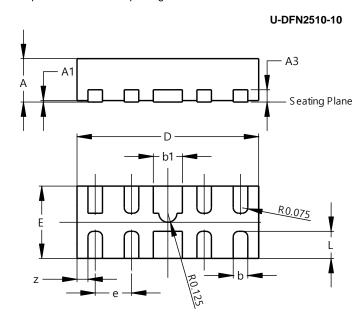






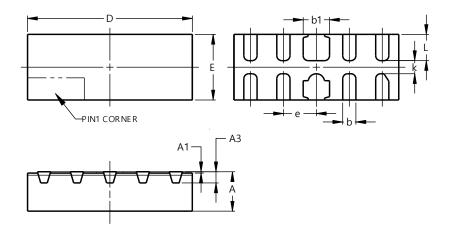
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2510-10								
Dim	Dim Min Max							
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.03					
A3	-	_	0.13					
b	0.15	0.25	0.20					
b1	0.35	0.45	0.40					
D	2.450	2.575	2.500					
е	1	_	0.50					
Е	0.950	1.075	1.000					
L	0.325	0.425	0.375					
Z	-	_	0.150					
All D	imensi	ons in	mm					

U-DFN2510-10 (Type CJ)



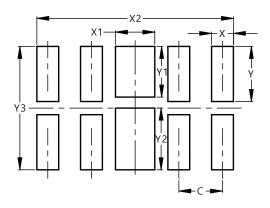
U-DFN2510-10									
(Type CJ)									
Dim	Min	Min Max Ty							
Α	0.545	0.605							
A1	0.00	0.05							
А3	0.	152RE	F						
b	0.150	0.250							
b1	0.350	0.450							
D	2.450	2.575	-						
Е	0.950	1.075							
е			0.500						
Е	0.950	1.075	1.000						
L	0.350 0.450								
k	k 0.200REF								
AII D	imensi	ons in	mm						



Suggested Pad Layout

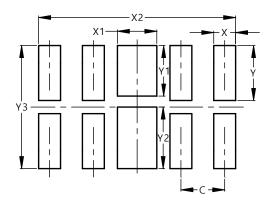
Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2510-10



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Υ	0.625
Y1	0.575
Y2	0.700
Y3	1.400

U-DFN2510-10 (Type CJ)



Dimensions	Value
	(in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Υ	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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